NSN 5961-01-186-3898

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-186-3898 **Inclosure Material:** Metal **Overall Length:** 0.210 inches **Terminal Length:** Between 1.500 inches and 1.800 inches **Overall Diameter:** 0.230 inches **Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: **Electrode Internally-electrically Connected To Case:** Anode **Mounting Method: Terminal Terminal Circle Diameter:** 0.100 inches **Features Provided:** Hermetically sealed case and mounting pad **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 30.0 on voltage, forward voltage drop, dc **Current Rating Per Characteristic:** 175.00 milliamperes forward current, average absolute **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: pnpnp **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

NO Fiig:

. ...9.

A110a0